



# MOSFET

## OptiMOS<sup>™</sup>3 Power MOS Transistor Chip

- N-channel enhancement mode
- · For dynamic characterization refer to the datasheet of IPD060N03L G
- AQL 0.65 for visual inspection according to failure catalogue
- Electrostatic Discharge Sensitive Device according to MIL-STD 883C
- Die bond: soldered or glued
- Backside metallization: NiV system
- Frontside metallization: AICu system
- · Passivation: nitride + imide

#### Table 1 **Key Performance Parameters**

Parameter	Value	Unit
V <sub>(BR)DSS</sub>	30	V
R <sub>DS(on)</sub>	6.0 <sup>1)</sup>	mΩ
Die size	2.26 x 1.24	mm <sup>2</sup>
Thickness	175	μm









Type / Ordering Code	Package	Marking	Related Links
IPC028N03L3	Chip	not defined	-

#### **Electrical Characteristics on Wafer Level** 1

at  $T_i = 25^{\circ}$ C, unless otherwise specified

## Table 2

Devemeter	Symbol	Values		llait	Note / Test Condition	
Parameter		Min.	Тур.	Max.	Unit	Note / Test Condition
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	30	-	-	V	V <sub>GS</sub> =0 V ,/ <sub>D</sub> =1 mA
Gate threshold voltage	V <sub>GS(th)</sub>	1	-	2.2	V	V <sub>DS</sub> =V <sub>GS</sub> , <i>I</i> <sub>D</sub> =250 μA
Zero gate voltage drain current	I <sub>DSS</sub>	-	0.1	2	μA	V <sub>GS</sub> =0 V , V <sub>DS</sub> =30 V
Gate-source leakage current	I <sub>GSS</sub>	-	10	100	nA	V <sub>GS</sub> =20 V ,V <sub>DS</sub> =0 V
Drain-source on- resistance	R <sub>DS(on)</sub>	-	5 <sup>2)</sup>	50 <sup>3)</sup>	mΩ	V <sub>GS</sub> =10 V , <i>I</i> <sub>D</sub> =2.0 A
Reverse diode forward on-voltage	V <sub>SD</sub>	-	0.86	1.1	V	V <sub>GS</sub> =0 V ,/ <sub>F</sub> =1A

 $<sup>^{1)}</sup>$  packaged in a PG-TO252-3 (see ref. product)  $^{2)}$  typical bare die  $R_{\rm DS(on)};~V_{\rm GS}$ =10 V, when used with 1x500µm Al-wedge

<sup>&</sup>lt;sup>3)</sup> limited by wafer test-equipment

Figure 1

# 2 Package Outlines





Outline Chip, dimensions in  $\mu m$ 



## **Revision History**

IPC028N03L3

### Revision: 2017-08-25, Rev. 2.6

Previous Revision				
Revision	Date	Subjects (major changes since last revision)		
2.5	2014-07-23	Release of Final Version		
2.6	2017-08-25	Update Typ Rds(on)		

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